

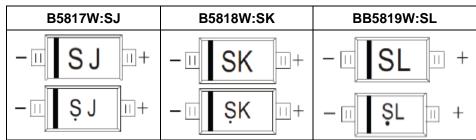
Green Products

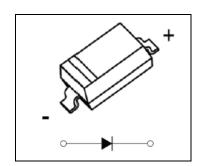
B5817W-B5819W SCHOTTKY BARRIER DIODE

Features:

- For use in low voltage, high frequency inverters
- Free wheeling, and polarity protection applications.

Marking:

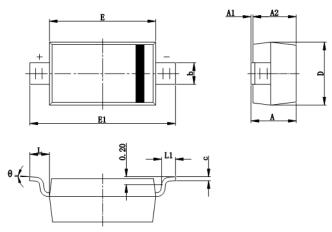




The marking bar indicates the cathode

Solid dot = Green molding compound device, if none, the normal device.

Mechanical Dimensions: In mm/Inches



Symbol	Dimensions In Millimeters		Dimensions In Inches		
	Min	Max	Min	Max	
Α	1.050	1.250	0.041	0.049	
A1	0.000	0.100	0.000	0.004	
A2	1.050	1.150	0.041	0.045	
b	0.450	0.650	0.018	0.026	
С	0.080	0.150	0.003	0.006	
D	1.500	1.700	0.059	0.067	
E	2.600	2.800	0.102	0.110	
E1	3.550	3.850	0.140	0.152	
L	0.500 REF		0.020 REF		
L1	0.250	0.450	0.010	0.018	
θ	0°	8°	0°	8°	

SOD-123

- China Germany Korea Singapore United States
 - http://www.smc-diodes.com sales@ smc-diodes.com •



Green Products

Ordering Information:

Device	Package	Shipping
B5817W-5819W	SOD-123(Pb-Free)	3000pcs / reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

Maximum Ratings @T_A=25°C unless otherwise specified

Parameter	Symbol	B5817W	B5818W	B5819W	Unit
Non-Repetitive Peak Reverse Voltage	V_{RM}	20	30	40	
Peak Repetitive Reverse Voltage	V_{RRM}				
Working Peak Reverse Voltage	V_{RWM}	20	30	40	V
DC Blocking Voltage	V_R				
RMS Reverse Voltage	$V_{R(RMS)}$	14	21	28	V
Average Rectified Output Current	Io	1			Α
Non-repetitive Peak Forward Surge Current @t=8.3ms	I _{FSM}	9			Α
Repetitive Peak Forward Current	I _{FRM}	1.5			Α
Power Dissipation	P_{D}	500			mW
Thermal Resistance from Junction to Ambient	R _{⊝JA}	200		°C/W	
Junction Temperature	T _j		125		°C
Storage Temperature	T _{stg}		-55~+150		°C

Electrical Characteristics @T_A=25°C unless otherwise specified

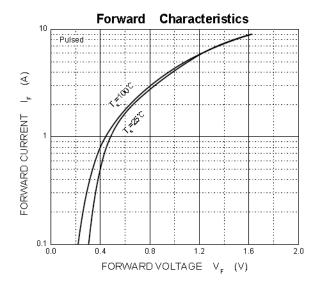
Parameter	Symbol	Test conditions		Min	Max	Unit
Reverse breakdown voltage	$V_{(BR)}$	I _R =1mA				
			B5817W	20	-	V
			B5818W	30	-	V
			B5819W	40	-	
Reverse voltage leakage current	I _R	V _R =20V	B5817W			
		V _R =30V	B5818W	-	1	mΑ
		V _R =40V	B5819W			
Forward voltage	V _F	B5817W	I _F =1A		0.45	
			I _F =3A	-	0.75	
		B5818W	I _F =1A		0.55	
			I _F =3A	-	0.875	V
		B5819W	I _F =1A		0.60	
			I _F =3A	_	0.90	
Diode capacitance	C _D	V _R =4V, f=1MHz		-	120	pF

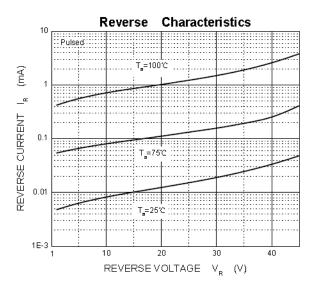
[•] China - Germany - Korea - Singapore - United States •

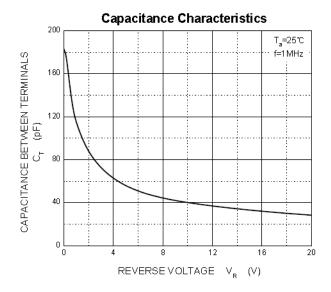
[•] http://www.smc-diodes.com - sales@ smc-diodes.com •

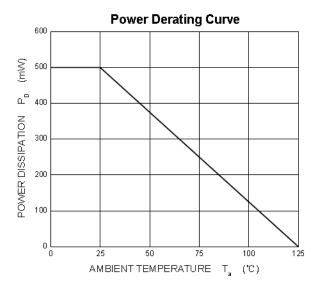


Green Products

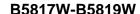








[•] http://www.smc-diodes.com - sales@ smc-diodes.com •





Green Products

DISCLAIMER

- 1- The information given herein, including the specifications and dimensions, is subject to change without prior notice to improve product characteristics. Before ordering, purchasers are advised to contact the SMC Sangdest Microelectronics (Nanjing) Co., Ltd sales department for the latest version of the datasheet(s).
- 2- In cases where extremely high reliability is required (such as use in nuclear power control, aerospace and aviation, traffic equipment, medical equipment, and safety equipment), safety should be ensured by using semiconductor devices that feature assured safety or by means of users' fail-safe precautions or other arrangement.
- 3- In no event shall SMC Sangdest Microelectronics (Nanjing) Co., Ltd be liable for any damages that may result from an accident or any other cause during operation of the user's units according to the datasheet(s). SMC Sangdest Microelectronics (Nanjing) Co., Ltd assumes no responsibility for any intellectual property claims or any other problems that may result from applications of information, products or circuits described in the datasheets.
- 4- In no event shall SMC Sangdest Microelectronics (Nanjing) Co., Ltd be liable for any failure in a semiconductor device or any secondary damage resulting from use at a value exceeding the absolute maximum rating.
- 5- No license is granted by the datasheet(s) under any patents or other rights of any third party or SMC Sangdest Microelectronics (Nanjing) Co., Ltd.
- 6- The datasheet(s) may not be reproduced or duplicated, in any form, in whole or part, without the expressed written permission of SMC Sangdest Microelectronics (Nanjing) Co., Ltd.
- 7- The products (technologies) described in the datasheet(s) are not to be provided to any party whose purpose in their application will hinder maintenance of international peace and safety nor are they to be applied to that purpose by their direct purchasers or any third party. When exporting these products (technologies), the necessary procedures are to be taken in accordance with related laws and regulations..